

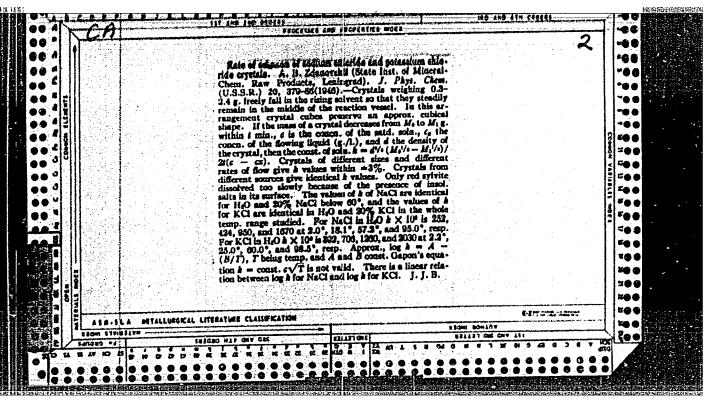
ZDANOVSKTY,A.B.

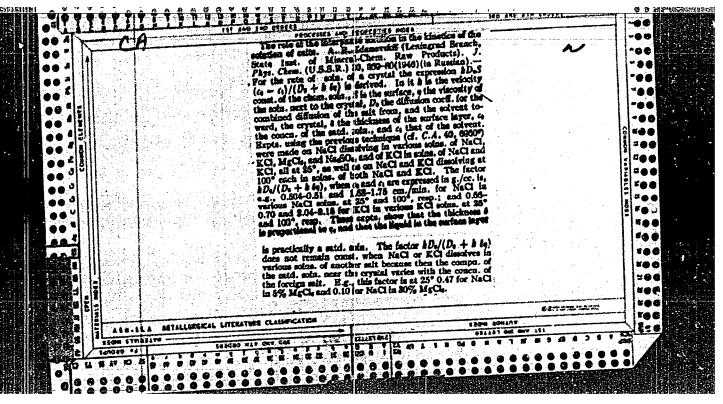
USSR

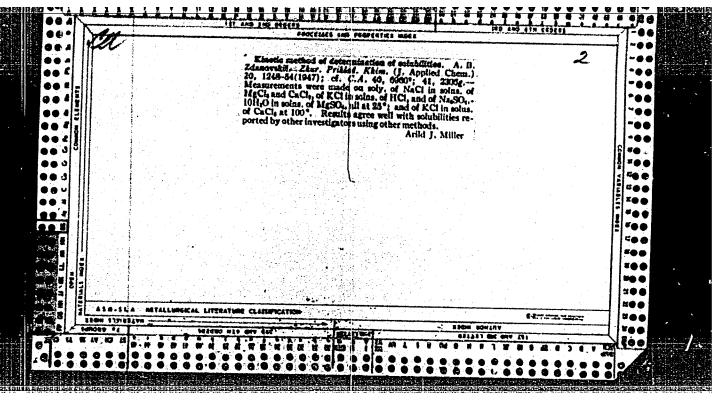
State Inst. Mining-Chem. Raw Materials, Leningrad Branch, (-1946-)

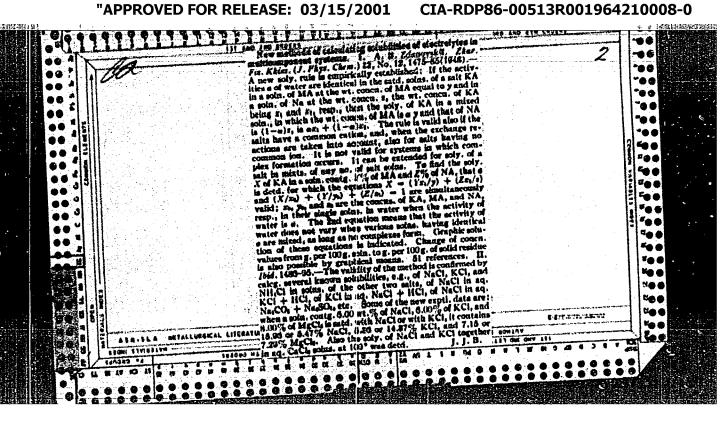
"The Velocity of Dissolution of NaCl and KCL Grystals."

Zhur. Fiz. Khim.,No. 4,1946.









Zdanovskiy, A. B. - "The kinetics of the dissolution of natural salts", (Report), Soobshch. o nauch. vabotakh chlenov Vsesoyuz. khim. o-va Im. Mendeleyeva, 1949, Issue 1, p. 19-21.

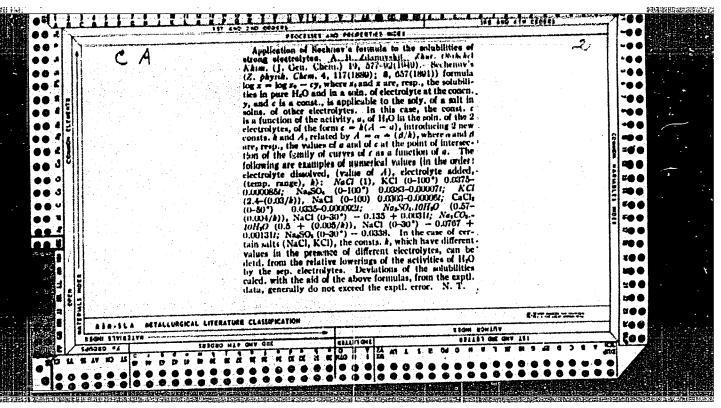
SO: U-4630, 16 Sept. 53, (Letopis 'Zhurnal 'nykh Statey, No. 23, 1949).

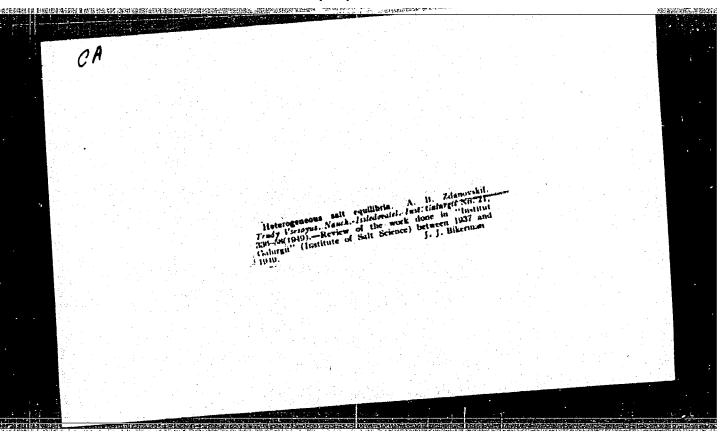
ZDANCVSKIY, A. E.

"The Application of Sechenov's Fortula to the Solubilities of Strong Electrolytes,"

Zhur. Obshch. Khim., 19., #4, 1949.

Mbr., All-Union Sci.-Res. Inst. Halurgy,-c1949-.





	ZDANOVSKIY, A.B. "Manual on solubility" by V.B.Kogan, V.M.Pridman, V.V.Kafarov. Reviewed by A.B.Zdanovskii. Zhur.neorg.khim. 8 no.4:1028-1030 (MIRA 16:3) Ap '63. (Solubility) (Kogan, V.B.)													
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L 12702-63 ACCESSION NR: AP3002930

8/9076/63/037/906/1268/1291

AUTHOR: Zdenovskiy, A. B.; Imsmutdinova, V. M.

TITLE: Mechanism of borate decomposition by sulfuric acid solution

SOURCE: Zhurnel fizicheskoy khmii, v. 37, no. 6, 1963, 1288-1291

TOPIC TAGS: borate decomposition, gypsum, borate, sulfuric acid, inoite, colemanite, hydroboracite, ulexite, solvent cycling method

ABSTRACT: The rate of dissolution of gypsum, B sub 2 0 sub 3 and four naturally occurring borates, inoite, colemanite, hydroboracite, and ulexite, in H sub 2 SO sub 4 solutions at 25 and 50 degrees has been determined, using the solvent cycling method in a close system. Gypsum films are formed on the surfaces of the dissolving crystals, which thereby limits the process of decomposition of the calcium borates in H sub 2 SO sub 4. The dissolution rates with respect to calcium referred to its content in unit volume of the mineral give curves with maxima. Orig. art. has: 4 figures and 6 equations.

ASSOCIATION: Kazanskiy gosudarstvennyty universitet (Kazan State University)

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ZDANOVSKIY, A. B.

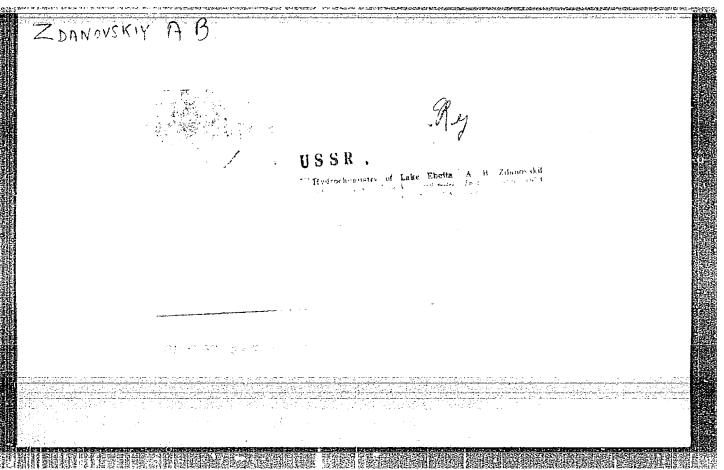
32538. Kinetika Protsessov ispareniya pastvorov. rastvoreniya i kristallizatsii soley. Trudy. Vsesoyuz. nauch.—issled. in—ta galurgii, vyo. 21, 1949, s. 371-96.—Bibliogr. 9 Mazv.

SC: Letopis' Zhurnal'nykh Statey, Vol. 44, Moskva, 1949

ZDANOVSKIY, A.B.; LYAKHOVSKAYA, Ye.I.; SHIEYMOVICH, R.E.; BUKSHTEYN, V.M., redaktor; VALYASHKO, M.G., redaktor; PEL'SH, A.D., redaktor.

[Handbook of experimental data on the solubility of multicomponent water-salt systems] Spravochnik eksperimental nykh dannykh po rast-vorimosti mnogokomponentnykh vodno-solevykh sistem. Vol.1 [Tri-component systems] Trekhkomponentnye sistemy. Leningrad, Gos. nauchno-nent systems] Trekhkomponentnye sistemy. Leningrad, Gos. nauchno-tekhnicheskoe izd-vo khimicheskoi lit-ry, 1953. 670 p. (MLRA 7:2)



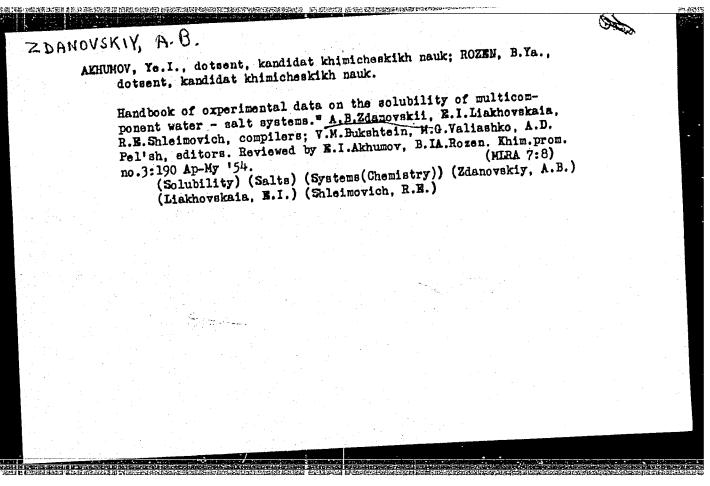


VIKTOROV, M.M.; ZDANOVSKIY, A.B., redaktor; ERLIKH, Ye.Ya., tekhnicheskiy redaktor

[Graphic calculations in the technology of minerals] Graficheskie raschety v tekhnologii mineral'nykh veshchestv. Izd. 2-e, perer. i dop. Leningrad, Gos. nauchno-tekhn. izd-vo khimicheskoi lit-ry, 1954. 502 p.

(MIRA 8:5)

(MIRA 8:5)



ZDANOVSKIY, A.B.; VYAZOVOV, V.V., red.; KOTS, V.A., red.; ERLIKH, Ye.Ya., tekhn. red.

[Kinetics of solution of natural salts in forced convection conditions] Kinetika rastvoreniia prirodnykh solei v usloviiakh vynuzhdennoi konvektsii. Leningrad, Gos. nauchno-tekhn. izd-vokhim. lit-ry. 1956. 218 p. (Leningrad. Vsesoiuznyi nauchno-is-sledovatel'skii institut galurgii. Trudy no.33). (MLRA 10:9) (Solution (Chemistry)) (Salts)

<u> Берракіл Тар.</u>

USSR/Thermodynamics. Thermochemistry. Equilibria. Physico-Chemical

Analysis. Phase Transition.

Abs Jour : Ref Zhur - Khimiya, No 8, 1957, 25128

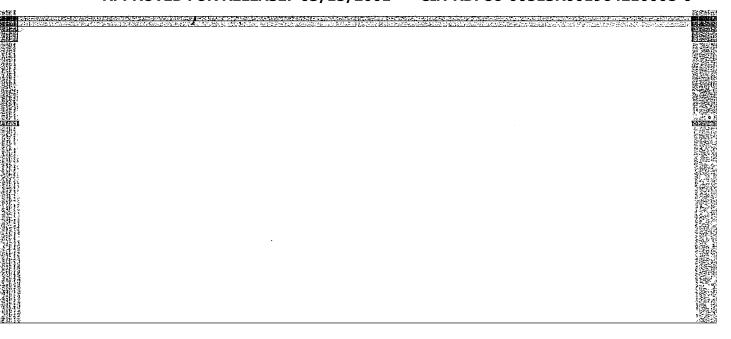
Author : A.B. Zdanovskiy

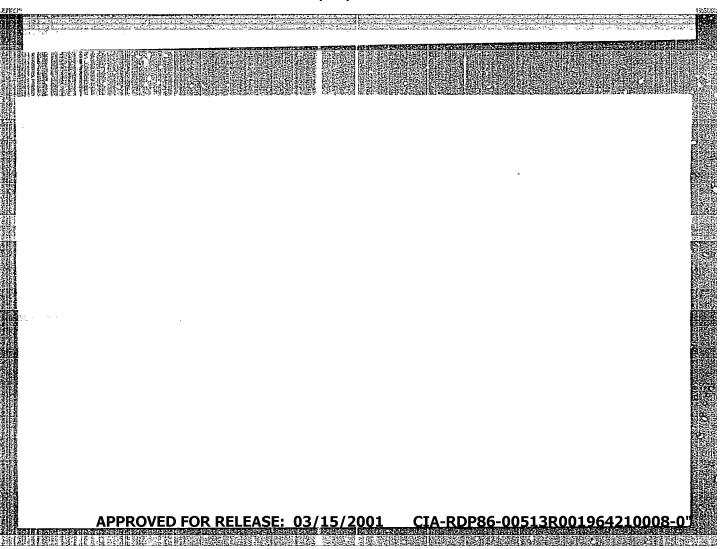
: Kinetic Method of Solubility Determination. Title

Orig Pub : Zh. neorgan, khimii, 1956, 1, No 6, 1279-1283

Abstract : A method of determination of the solubility of a substance based on the study of the speed of its dissolution in solutions of various concentration is proposed. In case of substances, the dissolution speed (V) of which is limited by the speed of the diffusion process $V = KS(C - C_x)$, where K is a constant (dissolution speed factor), S is the surface of the dissolving substance, C is the solubility, and C_{χ} is the solution concentration. It is possible to compute the value of C corresponding to V=0, or to find it from the graph of the interdependence of V and C, by determine V for solutions of several different concentrations near the saturation. The proposed method was used for the determination of the solubility of NaCl in concentrated solutions of MgCl2 and CaCl2 at 250; the results agreed well with bibliographical data. This method

Card : 1/2





ZDANOVSKIY, A.B.

Additivity of the viscosity logarithms of liquid mixtures.
Zhur.fiz.khim. 34 no.6:1380-1381 Je '60.
(MIRA 13:7)

1. Kazanskiy gosudarstvennyy universitet.
(Viscosity) (Mixtures)

ZDANOVSKIY, A.B.; DERYABINA, L.D.

Heats of mixing of electrolyte solutions. Part 2. Zhur. fiz. khim. 39 no.4:921-925 Ap '65. (MIRA 19:1)

1. Kazanskiy gosudarstvennyy universitet imeni Ul'yanova-Lenina. Submitted Nov.22, 1963.

ZDANOVSKIY, A.B.; IVANOVA, F.I.,

Kinematic fluidity, a function of additive nature. Zhur. fiz. khim. 39 no.9:2275-2278 S.165. (MIRA 18:10)

1. Kazanskiy gosudarstvennyy universitet imeni V.I. Ul'yanova-Lenina.

ZDANOVSKIY, A.B.; DERYABINA, L.D.

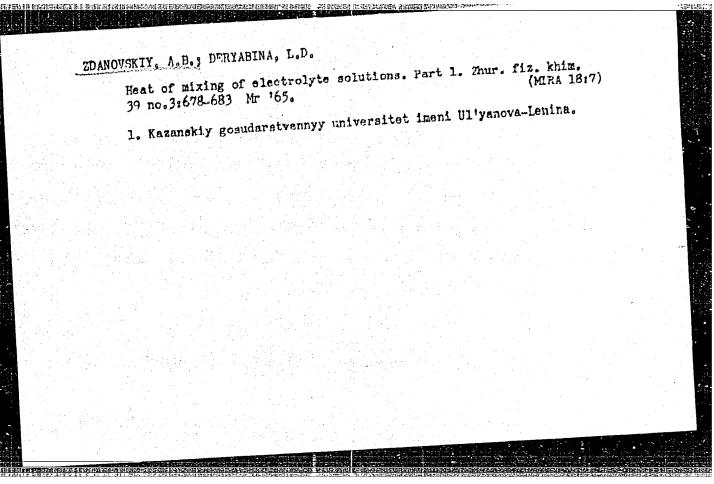
Heats of mixing of electrolyte solutions. Part 3. Zmur. fiz. khim. 39 no.6:1464-1468 Je '65. (MIRA 18:11)

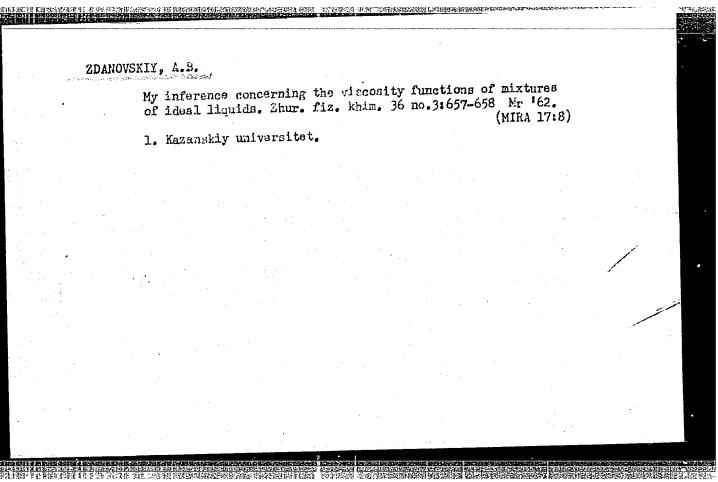
1. Kazanskiy gosudarstvennyy universitet imeni Ul'yanova-Lenina. Submitted June 18, 1964.

ZDANOVSKIY, A.B.; SPIRIDONOV, F.P.

Solubility of \angle - and β -modifications of CaSO₄.0,5H₂O and CaSO₄.2H₂O. Zhur.neorg.khim.ll no.1:20-24 Ja '66. (MIRA 19:1)

1. Submitted June 8, 1964.





(MIRA 17:1)

ZDANOVSKIY, A.B.; IMAMUTDINOVA, V.M.

Mechanism of the solution of naturally occurring borates in hydrochloric acid solutions. Zhur. fiz. khim. 37 no.5:1095-

1099 My 163.

1. Kazanskiy gosudarstvennyy universitet.

ZDANOVSKIY, A.B.; IMAMUTDINOVA, V.N.

Kinetics of solution of natural borates in hydrochloric acid

Kinetics of solutions. Zhur. prikl. khim. 36 no.8:1675-1680 Ag '63.

Solutions. Zhur. prikl. khim. 36 no.8:1675-1680 Ag '63.

(MIRA 16:11)

1. Kazanskiy gosudarstvennyy universitet imeni V.I. Ul'yanova
Lenina.

ZDANOVSKIY, A.B.; IMAMUTDINOVA, V.M.

Mechanism of borate decomposition by H_ZSO₄ solutions. Zhur.

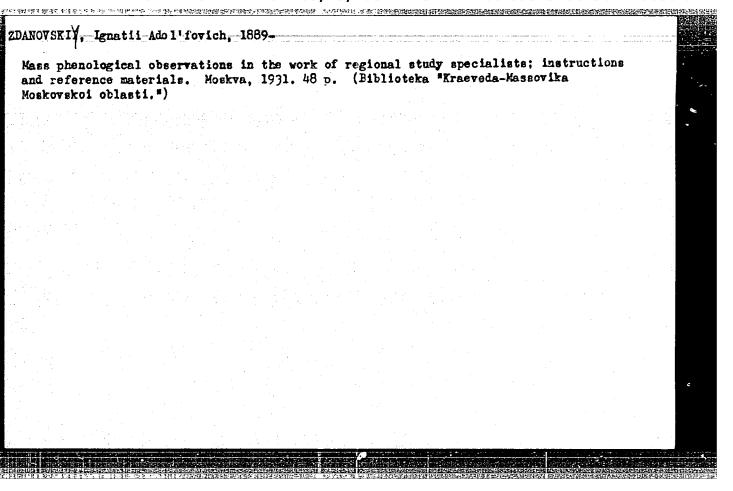
fiz. khim. 37 no.6:1288-1291 Je '63. (MIRA 16:7)

l. Kazanskiy gosudarstvennyy universitet.
(Borates) (Shifuric acid)

ZDANOVSKIY, A.B.; SOLOV'YEVA, Ye.F.; EZROKHI, L.L.; LYAKHOVSKAYA,
Ye.I.; VYAZOVOVA, V.V., red.; PEL'SHA, A.D., red.; KOTS, V.A.,
red.; LEVIN, S.S., tekhn. red.; ERLIKH, Ye.Ya., tekhn. red.

[Manual of experimental data on the solubility of salt systems] Spravochnik eksperimental nykh dannykh po rastvorimosti solevykh sistem. Leningrad, Gos. nauchno-tekhn.izd-vo khim. lit-ry. Vol.3. [Two-component systems; elements of the I group and their compounds] Dvukhkomponentnye sistemy; elementy I gruppy i ikh soedineniia. Sost. A.B.Zdanovskii i dr. Pod red. V.V. Vinzovova, A.D.Pel'sha, 1961. 2224 p. (MIRA 15:3)

l. Leningrad. Vsesoyuznyy nauchno-issledovatel'skiy institut
galurgii.
(Salts) (Systems (Chemistry)) (Solubility)



MAS THE

Device for tissue culture in the air with 5% of carbon dioxide.

Vop. virus. 9 nc.6:723-725 N-D *64.

1. Institut poliomiyelita i virusnykh entsefalitov AMN SSSR,

CIA-RDP86-00513R001964210008-0 "APPROVED FOR RELEASE: 03/15/2001

ZDANOVSKIY, M. 36648. Zdanovskiy, M. Oborudovaniye Na polnyy khod. (Ispol'zovaniye nevyyavlennykh Rezervov). Ill. S. vetsrumb. Tekhnika ---- Kolodezhi,

1949, No. 11, c. 12-13.

SO: Letopis' Zhurnal' nykh Statey, Vol. 50, Moskva, 1949

ZDANOVSKIY, M.

20647 Zdanovskiy, M. i Moratev, B. Bri Tady otlichnogo Kachestva. / Razvertyvaniye na mosk. prediriyatiyakh sots. sorevnovaniya za vysokoye Kachestvo produktsii po initsiative A. Chetkiku/. I 11. S. Vetsrumb. Tekhnika — molodezhi, 1949, No. 5, s. 6-8

SO: LETOPIS ZHURNAL STATEY - Vol. 28, Moskva, 1949

PANFILOV, G.; ZDANOVSKIY, S.

Experiment verified by life. Okhr, truda i sots. strakh. no.1:42-44
J1 '58. (MIRA 11:12)

1. Predsedatel' kemissii ekhrany truda Pervege gesudarstvennege pedshipnikevege zaveda (fer Panfilev). 2. Nachal'nik etdela bezepasnesti Pervege gesudarstvennege pedshipnikevege zaveda (fer Zdanovskiy).

(Industrial safety)

ZDANOVSKIY, S.F. Mechanization facilitates the labor. Bezop.trude v pron. 2 no.3:31 Mr '58. (MIRA 11:3) 1. Hachal'nik otdela tekhniki bezopasnosti 1-go Gosudarstvennogo podshipnikovogo zavoda. (Automatic control)

NESTERENKO, M.Z.; ZDANOW, W.M.; ZUKOWSKI, A.M.; Tlum: dr.med. ADONAJLO, A.

Studies on the epidemiology of influenza A2. Przegl. epidem. 15 no.3:265-278 '61.

1. Instytut Wirosologii im. D.J. Iwanowskiego ANM ZSRR, Moskwa. (INFLUENZA ASIAN epidemiol)

ZDANOW, W.M.; FADEEVA, L.L.

Experimental data and observations on children immunized with allantois tissue. Med. dosw. mikrob. 9 no.4:419-424 1957.

1. Z Instytutu Wirusologii im. Iwanowskiego A. M. N. ZSHR.

(MEASLES, immunology,
vaccine, passage in tissue culture & prep. of allantois tissue vaccine (Pol))

ZDANOWICZ, E.

Work involved in the preparation of a plan for the turnover of goods in 1955, Poradnik. p(RCINIK SPOLDZIELCA, Warszawa, Vol. 7, no. 21, Nov. 195h.)

SO: Monthly List of East European Accessions, (EEAL), LC, Vol. 4, No. 6, Jun. 1955, Uncl.

ACCESSION NR: AP4041220

0/0030/64/006/001/0227/0234

AUTHOR: Zdanowicz, L.; Zdanowicz, W.

TITLE: Semiconducting properties of Cd sub (3 - x) Zn sub xAs sub 2 type solid solutions

SOURCE: Physica status solidi, v. 6, no. 1, 1964, 227-234

TOPIC TAGS: cadmium zinc arsenide, solid solution semiconductor, Hall effect, activation energy change, phase transition

ABSTRACT: As the compounds of arsenic with cadmium and zinc show interesting and completely different semiconducting properties, the electric properties of the three-component system $Cd_3As_2-Zn_3As_2$ in the semibinary range were examined. Synthesis of $Cd_2-Zn_2As_2$ was achieved by direct melting of the components or by melting definite quantities of Cd_3As_2 and Zn_3As_2 . The arsenic used was of semiconductor purity and the zinc and cadmium were either distilled three times or distilled and purified by zone melting. The materials were melted in silica tubes covered inside with carbon to prevent adhesion

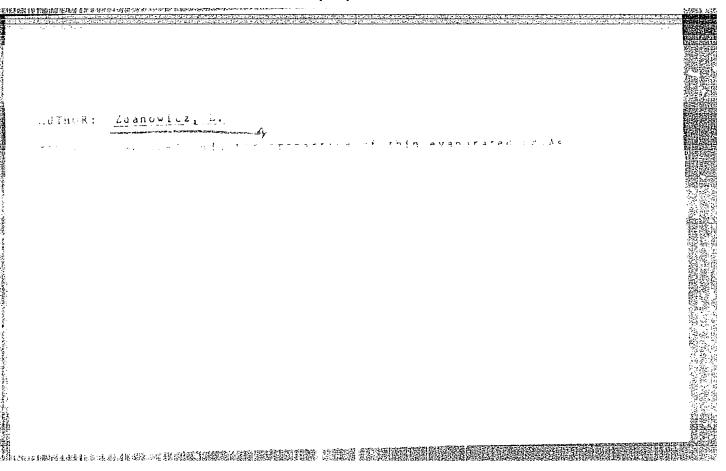
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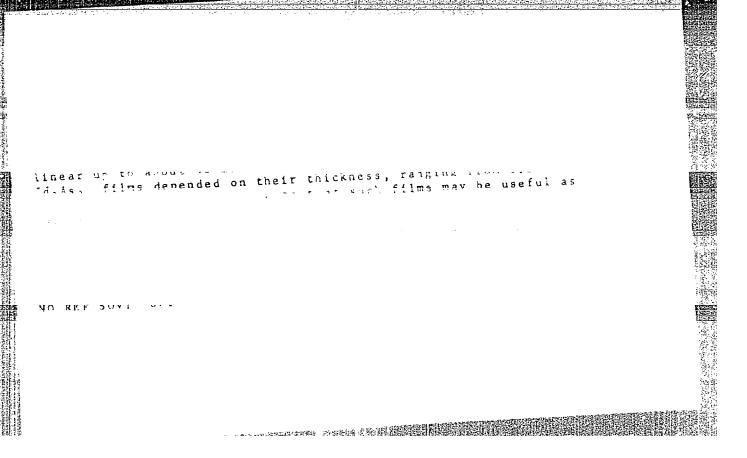
ACCESSION NR: AP4041220

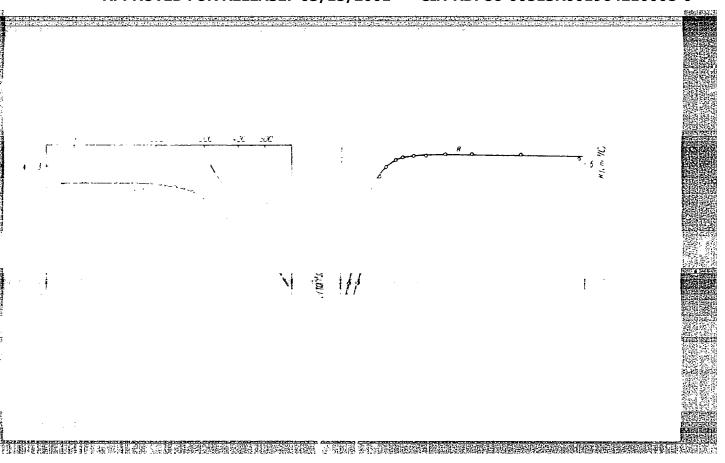
of the material to the tube wall. The temperature of synthesis ranged from 900C to 1100C. At room temperature the samples were found to be semiconducting, being n-type for $0 \le x \le 1.35$ and p-type for $1.5 \le x \le 3$. The following relations were measured for these samples: 1) the temperature vs the resistivity of the samples $(0 \le x \le 3)$; the resistivity vs the Zn₃As₂ concentration at T = 500K; the dependence of the Hall coefficient on 1000/T for n-type samples and for p-type samples; the concentration of current carriers in samples vs the Zn₃As₂ concentration (T = 100K); the temperature dependence of the Hall mobility of electrons and holes in the samples; the dependence of the band gap in samples $(0 \le x \le 3)$ on the Zn₃As₂ concentration; the dependence of the lattice constants in the samples on the Zn₃As₂ concentration. A proposed phase system for Cd₃-x²n₄As₂ is presented. The transition from n- to p-type takes place at about 47 mole Z Zn₃As₂ with a transition region of Z 3 mole Z Zn₃As₂, an abrupt change in the activation energy being noted in this transition region. The concentration of current carriers varied from Z 2.5 x Z 10 m concentration of current carriers varied from Z 2.5 x Z 10 m concentration of current carriers varied from Z 2.5 x Z 10 m concentration of current carriers varied from Z 2.5 x Z 10 m concentration of current carriers varied from Z 2.5 x Z 10 m concentration of current carriers varied from Z 2.5 x Z 10 m concentration of current carriers varied from Z 2.5 x Z 10 m concentration of current carriers varied from Z 2.5 x Z 10 m concentration of current carriers varied from Z 2.5 x Z 10 m concentration of current carriers varied from Z 2.5 x Z 10 m concentration of current carriers varied from Z 2.5 x Z

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ZDANOWICZ, P.

Boron-carbon resistors. p. 215. (TELE-RADIO. Vol. 2, no. 5, May 1957, Warszawa, Poland)

SO: Monthly List of East European Accessions (EEAL) LC. Vol. 6, No. 12, Dec. 1957.
Uncl.

ZDANOWICZ, W.; HENKIF, Z.

Some electric properties of Zn3P2. Bul clim PAN 12 no.10:729-734 '64.

1. Institute of Structural Research, Wroclaw, of the Polish Academy of Sciences. Submitted August 7, 1964.

ACCESSION NR: AP4041220

G/Q030/64/006/001/0227/0234

AUTHOR: Zdanowicz, L.; Zdanowicz, W.

TITLE: Semiconducting properties of Cd sub (3 - x) Zn sub xAs sub 2 type solid solutions

SOURCE: Physica status solidi. v. 6, no. 1, 1964, 227-234

TOPIC TAGS: cadmium zinc arsenide, solid solution semiconductor, Hall effect, activation energy change, phase transition

ABSTRACT: As the compounds of arsenic with cadmium and zinc show interesting and completely different semiconducting properties, the electric properties of the three-component system ${\rm Cd_3As_2-Zn_3As_2}$ in the semibinary range were examined. Synthesis of ${\rm Cd_2-Zn_2As_2}$ was achieved by direct melting of the components or by melting definite quantities of ${\rm Cd_3As_2}$ and ${\rm Zn_3As_2}$. The arsenic used was of semiconductor purity and the zinc and cadmium were either distilled three times or distilled and purified by zone melting. The materials were melted in silica tubes covered inside with carbon to prevent adhesion

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ACCESSION NR: AP4041220

of the material to the tube wall. The temperature of synthesis ranged from 900C to 1100C. At room temperature the samples were found to be semiconducting, being n-type for $0 \le x \le 1.35$ and p-type for $1.5 \le x \le 3$. The following relations were measured for these samples: 1) the temperature vs the resistivity of the samples $(0 \le x \le 3)$; the resistivity vs the Zn₃As₂ concentration at T = 500K; the dependence of the Hall coefficient on 1000/T for n-type samples and for p-type samples; the concentration of current carriers in samples vs the Zn₃As₂ concentration (T = 100K); the temperature dependence of the Hall mobility of electrons and holes in the samples; the dependence of the band gap in samples $(0 \le x \le 3)$ on the Zn₃As₂ concentration; the dependence of the lattice constants in the samples on the Zn₃As₂ concentration. A proposed phase system for Cd₃ Zn₄As₂ is presented. The transition from n- to p-type takes place at about 47 mole Z Zn₃As₂ with a transition region of Z 3 mole Z Zn₃As₂, an abrupt change in the activation energy being noted in this transition region. The concentration of current carriers varied from Z 3. Z 1018 cm⁻¹ (Cd₂As₂) to 6.2 x 1016 cm⁻¹ (Cd₁.65Zn₁.35As₂) at Z 100K. The band gap (activation energy) increased linearly from

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ZDANOWICZ, W.; LUKASZEWICZ, K.; TRZEBIATOWSKI, W.

Crystal structure of the semiconducting system Cd3As2-Zn3As2.
Bul chim PAN 12 no. 3:169-176 '64.

1. Institute of Structural Research, Polish Academy of Sciences, Wroclaw. Presented by W.Trzebiatowski.

ZDANOWICZ, W.; TRUMPOWSKI, B.

Thermoelectric properties of $Cd_{3-x}Zn_x$ As 2 -type solid solutions. Acta physica Pol 26 no.6:1205-1210 '64

1. Department of Physics of Wroclaw Technical University. Submitted June 16, 1964.

ACCESSION NR: AP4041474 P/0045/64/025/005/0663/0673

AUTHOR: Zdanowicz, W. (Zhdanovich, Vitol'd)

TITLE: Hagnetic reluctance of cadmium, arsenide in a temperature range from 1.6 to 300K

SOURCE: Acta physica polonica, v. 25, no. 5, 1964, 663-673

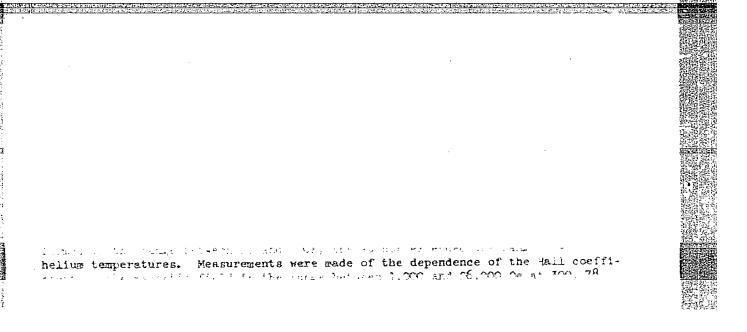
TOPIC TAGS: Cd₃As₂, Cd₃As₂ galvanomagnetic property, Cd₃As₂ thermo-electric property, Cd₃As₂ optical property, Cd₃As₂ reluctance, Cd₃As₂ Hall effect

ABSTRACT: The Hall effect and the magnetic reluctance of an n-type₁₈ cm⁻³ were investigated at temperatures of 1.6, 4.2, 78 and 300K classical theory of reluctance for strong magnetic fields is not (pH = 13), the reluctance for strong magnetic fields is not (pH = 13), the reluctance 1s proportional to H² only in weak magnetic Gard

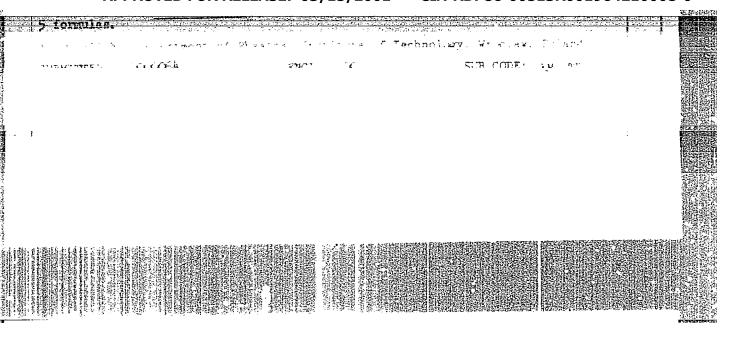
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	ACCESSION NR: AP4041474	
	fields (μ H < 1). At T = 78K, this proportionality is not conserved either for transverse or longitudinal reluctance, which differ very	
	whole range of investigated fields (pH > 1) in the	
	of reluctance on temperature and the magnetic field can be expressed by an empirical formula, $\Delta\rho/\rho_0 = (A\nu_{\rm H}H)^2$, where A is the constant exponent of H depending on temperature.	
	The geometric effect which includes, and up is the Hall mobility.	
	itself mostly in weak magnetic fields (uH < 1). In very strong fields	
	ASSOCIATION: Politechnika Wrockawska, Katedra Pizyki, Wroclaw (Wroclaw Polytechnical Institute, Physics Faculty)	
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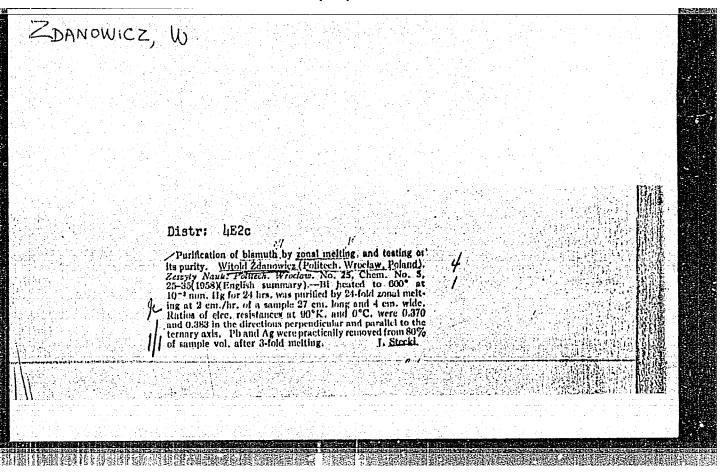
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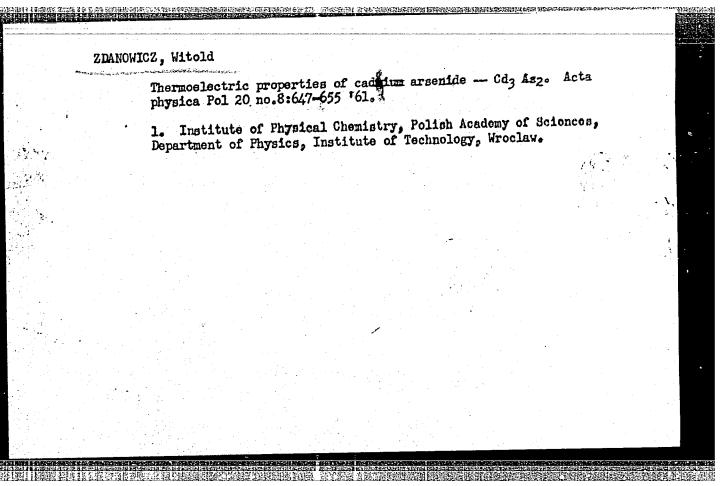








TRZEB	TRZEBIATOWSKI, W.; ZDANOWICZ, W.													
	Some electrical properties of cadmium arsenide Cd3As2. Bul chim PAN 8 no.9:511-516 '60.													
	1. Institute of Physical Chemistry, Polish Academy of Sciences and Department of Inorganic Chemistry, Technical University, Wroclaw. Presented by W. Trzebiatowski.													
and the second s	(Electricity) (Cadmium) (Arsenides)	,												
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推到某事件多级的名词复数的特性。而1883年,那些1000年,他们是1985年,1986年,1986年,1986年,1986年,1986年,1986年,1986年 GE/0030/66/016/002/K129/K131 EXT(1)/EXT(m)/T/EMP(t)/ETI SOURCE CODE: L h1101-66 6 AP6027759 ACC NRI Zdanovicz, W.; Wojakowski, A. ORG: Institute of Structural Research, Polish Academy of Sciences, AUTHOR: Wroclaw TITLE: Semiconducting properties of CdP4 no. 2, 1966, Kl29-Kl31 SOURCE: Physica status solidi, v. 16, TOPIC TAGS: semiconducting material, thermoelectric power, resistivity, Hall constant, CADMIUM COMPOUND, PHOSPHORUS, POLY CRYSTAL ABSTRACT: The semiconducting properties of CdP4 were investigated by means of electrical and optical measurements. CdP4 was obtained by sdturating CdP2 or Cd3P2 with phosphorus vapors at a pressure of 6 to 10 atm. The synthesis was carried out in evacuated silica tubes containing CdP2 or Cd3P2 at one end (the temperature of this zone was about 700C) while red phosphorus was placed in the other end (the temperature of this zone was about 500 to 540C). Thrice-distilled phosphorus and cadmium purified by zone melting were used. In this way CdP, was obtained in bulk polycrystalline form or as small, well-formed single crystals. The resistivity, Hall constant, and thermoelectric power for both poly- and monocrystalline CdP4 specimens were measured Card 1/2

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in the temperature range from 100 to 600K. CdP4 was found to be a ptype semiconductor. Its resistivity for both poly- and monocrystalline specimens at 300K is of the order of 2 to 8 ohm centimeter. The Hall constant for polycrystalline material at 300K is $R_{\rm H}$ = 400 cm³/C (p = 2 x 10¹⁶ cm⁻³). The thermoelectric power a of polycrystalline CdP4 is about 600 uv/°C at 300K. The optical measurements were carried out at room temperature using large polycrystalline CdP4 specimens 0.15 and 0.25 mm thick. The transmittance and reflectivity were measured from 0.5 to 3 µm. The maximum value of the absorption coefficient was 600 cm-1 , decreasing beyond the absorption edge to about 150 cm-1. The width of the forbidden band AEopt = 1.0 eV. The above value is in satisfactory agreement with those estimated from measurements of the resistivity and Hall constant. The authors express their sincere thanks for the help and interest of Professor W. Trzebiatowski, who supervised these investigations. Orig. art. has: 1 formula and 2 figures. [JA]

SUB CODE: 20/ SUBM DATE: 21Jun66/ ORIG REF: 002/ OTH REF: 002 SOVEREF: 001/ ATD PRESS: 5057

Card 2/2 hs

26.2532

AUTHOR:

Zdanowicz, Witold

TITLE:

Thermoelectrical properties of cadmium arsenide - Cd3As2

PERIODICAL:

Acta Physica Polonica, v. 20, no. 8, 1961, 647-655

TEXT: Measurements of the temperature dependence of the thermo-emf between Cd_3As_2 and Cu permit conclusions as to the position of the Fermi level, the degree of degeneracy of the electron gas, and the amount of the effective electron mass in Cd_3As_2 . Measurements of the thermo-emf and its temperature dependence $\alpha = f(T)$ at a mean temperature gradient from 10 to 12°C showed a continuous decrease of α from the value $\alpha = -60 \mu\text{v}/^{\circ}\text{K}$ at 300°K to $\alpha = -90 \mu\text{v}/^{\circ}\text{K}$ at 500°K from which it slightly rose again up to a value $\alpha = -85 \mu\text{v}/^{\circ}\text{K}$ at 700°K. Since in Cd_3As_2 the conditions developed by Tauc, J., Matyas, (Czech. J. Phys., 5, 369 (1955)) and Samoilovich, A. Ch., Korenblit, L. L. (Uspekhi. fiz. Nauk, 57, 577 (1955)) are correct, the reduced Fermi level $\eta = \frac{1}{2} \text{kT}$ can be calculated with known thermo-emf by

Card 1/6

Thermoelectrical properties of ...

means of

$$\alpha = \pm \frac{k}{e} \left\{ \frac{2+r}{1+r} \cdot \frac{F_{r+1}(\eta)}{F_r(\eta)} - \eta \right\}$$

where

$$F_r(\eta) = \int_0^\infty \frac{x^r}{1 + e^{x-\eta}} dx$$

(Fermi function). If η is plotted versus temperature, η decreases hyperbolically in the range of approximately 300°K ($\eta\approx4.8$) to 500°K; at approximately 500°K it attains its minimum ($\eta=2.8$) after which it increases again and attains the value 3.1 at approximately 700°K. η never becomes smaller than 2, hence, the electron gas is degenerate. The Fermi level (= ηkT lies in the conduction band and is only weakly temperature-dependent; in the temperature range 290 to 700°K (varies between -0.12 ev and -0.17 ev as calculated from the bottom of the conduction band. 8 The electron mobility is calculated by multiplying the known term $\mu_H = \frac{8}{3\pi} (R\sigma)$ with the correction factor f_1 following from the temperature dependence of η and taking account of the degeneracy of the electron gas (Fig. 4). The Card 2/6

Thermoelectrical properties of ...

temperature course of the Hall mobility $\mu_{\mbox{\scriptsize H}}$ is shown in Fig. 4 with and without consideration of degeneracy. If, instead of Ro, To is plotted versus temperature, practically a straight line is obtained, which in turn indicates a degeneracy of the electron gas. Using

$$R_{n} = -\frac{3\pi}{8e} \cdot \frac{1}{n} \cdot f_{1}(\eta)$$

 $R_n = -\frac{3\pi}{8e} \cdot \frac{1}{n} \cdot f_1(\eta)$ (R Hall coefficient) the temperature dependence of the electron concentration n can be calculated (Fig. 6 with and without correction) which is connected with the effective electron mass by $n = \left(\frac{m_n^*}{m_o}\right)^{3/2} + \frac{2}{\sqrt{\pi}} F_{1/2}(\eta).$

$$n = \left(\frac{m_n^*}{m_n}\right)^{3/2} A \frac{2}{\sqrt{\pi}} F_{1/2}(\eta).$$

If the normalized effective electron mass m_n^*/m_0 resulting therefrom is plotted versus temperature, m_n^*/m_o remains practically constant between 290°K and approximately 440°K after which it increases like m*/mo~T0.9 The degeneracy of the electron gas is caused by the high carrier concen-Card 3/6

Thermoelectrical properties of ...

tration (2.5·10¹⁸ cm⁻³), the low activation energy (0.14 ev) and the small effective electron mass. The data on the width of the forbidden band which strongly diverge as a result of the different methods of measurement used (0.6 ev when measuring the optical absorption constant, 0.14 ev when measuring the electric conductivity) can be explained qualitatively, since due to the similarity between Cd₃As₂ and InSb the energy band model given by Burstein E.(Phys. Rev., 93, 632 (1954)) for InSb also holds for Cd₃As₂,

i.e., for measurements of the optical absorption edge only the direct transitions of optical electrons from the valence band to lower levels lying on the Fermi level in the conduction band are obtained. The author thanks Professor W. Trzebiatowski for supervising the studies and Mr. Raułuszkiewicz and Kołodziejczak of the Institute of Physics PAN in Warsaw for valuable remarks. There are 7 figures and 6 references: 4 Sovietbloc and 2 non-Soviet-bloc.

ASSOCIATION: Institute of Physical Chemistry Polish Academy of Sciences,

Department of Physics, Institute of Technology, Wrockaw

SUBMITTED: March 9, 1961

Card 4/6

POLAND/Solid State Physics - Processes of Crystallization and Crystal E-8

Morphology

Abs Jour : Ref Zhur - Fizika, No 3, 1958, No 6005

Author : Zdanowicz Witold

Inst : Not G iven

Title : Purification of Substances by Zonal Melting

Orig Pub : Postepy fiz., 1957, 8, No 2, 147-164

Abstract : No abstract

Card : 1/1

ANISIMOWICZ, Zofia; PIELOWSKA, Elzbieta; SZAWLOWSKI, Kazimierz; ZDANOWICZ, Zygmunt

Effect of somatotropin on the recovery of muscles in paresis and atrophy in poliomyelitis. Chir. narzad. ruchu ortop. pol. 27 no.4:511-516 '62.

1. Z Sanatorium Rehabilitacyjnego dla dzieci po H.M. w Gdansku Dyrektor: dr Z. Anisimowicz. (POLIOMYELITIS) (SOMATOTROPIN)

ZDANOWICZ, Z.

It is possible to accomplish the supply plan with a surplus. p. 4.

ROLNIK SPOKDZIELCA. (Centrala Rolniczej Społkzielni "Sampopomoc Chlopska") Warszawa, Poland. Vol. 8, no. 43, Oct. 1955.

Monthly list of East European Accessions (EEAI) LC, Vol. 9, no. 2, Feb. 1960.

Uncl.

JANCZURA, Ewa; ZDANOWSKA, Barbara

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1. Z Zakladu Bakteriologii Panstwowego Zakladu Higieny w Warszawie.

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TABEAU, Jerzy; WOJCIKIEWICZ, Olga; HLADIJ, Jaroslaw; CZARNECKA-CHONKO, Danta; ZDANOWSKA, Krystyna

Clinical significance of abnormally high T wave. I. Electrocardiographic aspects. Pol. tyg. lek. 19 no.35:1318-1321 31 Ag '64.

1. Z I Kliniki Chorob Wewnetrznych Akademii Medycznej w Krakowie (kierownik: prof. dr Leon Tochowicz).

KALUZNIACKA, Anna; ZDANOWICZ, Hanna

Results of treatment of rhoumatic children at the Rehabilitation Sanatorium in Krasnobrod. Pol. tyg. lek. 19 no.52:2001-2003 28 D'64.

1. Z II Kliniki Pediatrycznej Akademii Medycznej w Inblinie (kierownik: doc. dr.med. A. Gebala).

SZYBINSKI, Zbigniew; CIBA, Tadeusz; PYZIK, Zbigniew; ZDANOWSKA, Krystyna

Hypertension and the indices of thyroid function in simple goiter
and in hyperthyroidism. Fol. tyg. lek. 20 no.20:710-712 17 My 165.

1. Z I Kliniki Chorob Wewnetrznych AM w Krakowie (Kierownik: prof.
dr. Leon Tochowicz) i z Wojewoizkiej Poradni Endokrymologicznej dla
Doroslych w Krakowie (Kierownik: dr. med. Tadeusz Ciba).

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ZDANOWIKI

POLAND / Chemical Technology, Chemical Products and Their Application, Part 1. - Corrosion Pro-

tection Therefrom.

Abs Jour: Ref Zhur-Khimiya, No 18, 1958, 61326.

: Cyryl Niewiadomski, Antoni Zdanowski.

: Institute of Mechanics. Inst

: Aliting of Steel. 1. Properties of Alited Steel. Title

Orig Pub: Prace Inst. mech., 1957 (1958), 7, No 22, 11 - 19.

Abstract: The methods of preparation of low-carbon steel

surface for aliting were studied. The optimum for aliting are found in the result of a study of the effects of the surface preparation, bath temperature, duration of aliting and addition (Si, Si-Zn and Si-Cu) contents in the melt on the plasticity of Al coatings. Bibliography

with 29 titles.

Card 1/1

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ZDANGSKI Andreoj, mgr inz.

New Polish standard for steel boiler pipes. Wiad hut 16 no.3:
92-95 Mr 960.

HALAS, Andrzej; MORAW, Michal; SZRETER, Miroslaw; ZDANOWSKI, Jerzy

Technology of the nodistron digital indicator tube. Przegl
elektroniki 3 no.61336-338 Je '62.

1. Przemyslowy Instytut Elektroniki, Warszawa i Katedra Elektroniki,
Politechnika, Wroclaw.

Digital tube, I						
1. Katedra Ele	ektroniki,	Politecm	ika, wrocia	# .		
er de gebruik 1907 - De 1907 - British						
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AUTHORS: Halas, Andrzej, Moraw, Michał, Szreter, Mirosław, Zdanowski, Jerzy. The technology of the Nodistron type digital
TITLE: indicator tube indicator tube Przeglad Elektroniki, no.6, 1962, 336-338 PERIODICAL: Przeglad Elektroniki, no.6, 1962, 336-338 A prototype series of digital indicator tubes of TEXT: A prototype series of digital indicator tubes of Text: A prototype series of digital indicator tubes of A prototype series of digital indicator tubes of Text: A prototype series of digital indicator tubes of A prototype series of digital indicator tubes of

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The technology of the ...

spacers causing shorts. A 10-piece serie's is now being examined in the Dept. of Electronic Measurements of the Wrockaw Polytechnic. The work was started in 1959. There is 1 figure.

ASSOCIATION: Przemysłowy Instytut Elektroniki (Industrial Institute of Electronics

Card 2/2

ZDANOWSKI, R.

Maintenance of active telecommunication installations. p. 213.

PRZEGLAD KOLEJOWY ELEKTROTECHNICZNY. (Wydawnietwa Komunikacyjne) Warszawa, Poland, Vol. 11, no. 7, July 1959.

Monthly list of East European Accessions (EEAI) IC, Vol. 9, no. 1, Jan. 1960.

Uncl.

ZDANSKA- BRIMEKENOWAY.

POLAND/General Division, History, Classics, Personnel A-2

Abs Jour: Ref Zhur-Biologiia, No 5, 1958, 18845

Author : Zdanska-Brinckenowa M.

Inst:

Title : Jerzy Damski (21. VII. 1919-22.X.1956)

Orig Pub: Wszechswiat, 1957, No 2, 53-54

Abstract: An obituary of the Polish anthropologist Dambski,

the author of a number of works on the ethnogenesis and ancient history of the peoples of Western Asia

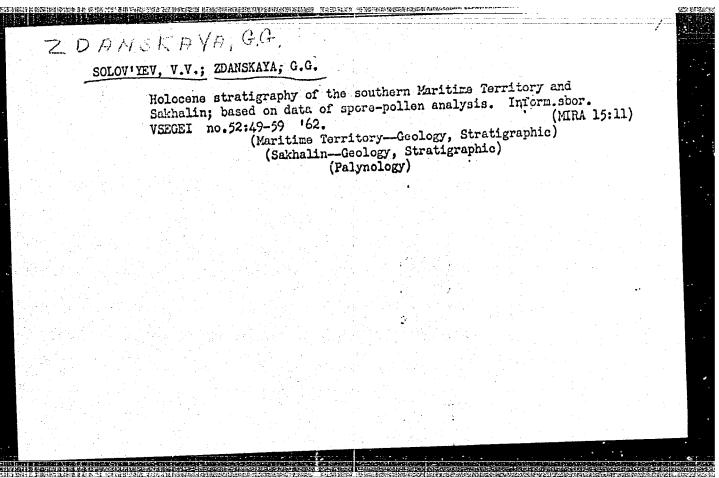
and Africa.

Card 1/1

ZDANSKA-BRINCKENOWA, M.

In connection with Rasza Szlep's article "Marginal Remarks on the Conference of Zoologists." p. hOl.
(KOSMOS BIOLOGIA. Vol. 6, no. h, 1957. Warszawa, Poland)

SO: Monthly List of East European Accessions (EEAL) LC. Vol. 6, no. 12, Dec. 1957.
Uncl.



ZDANSKIY, A.B.; SOLOV'YEVA, Ye.F.; EZROKHI, L.L.; LYAKHOVSKAYA, Ye.I.

Přinimali uchastiye: SHITIKOVA, V.S.; BEL'DY, M.P.; ROMANOVA,

V.A.; PEL'SH, A.D., red.; KOTS, V.A., red.; LEVIN, S.S., tekhn.

red.; ERLIKH, Ye.Ya., tekhn. red.

[Handbook of experimental data on the solubility of salt systems] Spravochnik eksperimental nykh dannykh po rastvorimosti solevykh sistem. Leningrad, Goskhimizdat. Vol.4.[Two-component systems; elements of the IInd group and their compounds] Dvukhkomponentrye sistemy; elementy II gruppy i ikh soedineniia. Sost. A.B.Zdanskii i dr. Pod red. A.D.Pel'sha, 1963. 2231-2878 p. (MIRA 17:2)

1. Leningrad. Vsesoyuznyy nauchno-issledovatel'skiy institut galurgii. 2. Fiziko-khimicheskaya laboratoriya Vsesoyuznogo nauchno-issledovatel'skogo instituta galurgii (for Shitikova, Bel'dy, Romanova).

